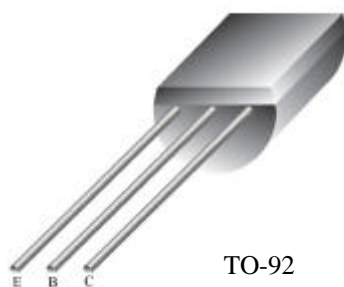
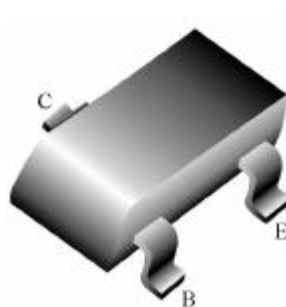


2N3904



TO-92

MMBT3904



SOT-23

E:Emitter B:Base C:Collector

NPN General Purpose Amplifier

This device is designed as a general purpose amplifier and switch. The useful dynamic range extends to 100mA as a switch and to 100 MHz as an amplifier.

Absolute Maximum Ratings* $T_A=25^{\circ}\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CEO}	Collector-Emitter Voltage	40	V
V_{CBO}	Collector-Base Voltage	60	V
V_{EBO}	Emitter-Base Voltage	6.0	V
I_C	Collector Current – Continuous	200	mA
T_J, T_{STG}	Operating and Storage Junction Temperature Range	-55 to +150	$^{\circ}\text{C}$

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics $T_A=25^{\circ}\text{C}$ unless otherwise noted

Symbol	Characteristic	Max		Units
		2N3904	MMBT3904	
P_D	Total Device Dissipation Derate above 25°C	625	350	mW
		5.0	2.8	mW/ $^{\circ}\text{C}$
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3		$^{\circ}\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	375	$^{\circ}\text{C}/\text{W}$